TOSHIBA TLRH157P

TOSHIBA LED LAMP InGaA&P RED LIGHT EMISSION

TLRH157P

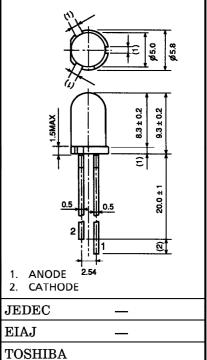
PANEL CIRCUIT INDICATOR

- 5 mm DIAMETER (T1-3/4)
- InGaA&P RED LED
- All Plastic Mold Type.
- Colorless Clear Lens
- Low Drive Current, High Intensity Red Light Emission Recommended Forward Current : $I_F = 1 \sim 20 \text{ mA}$ (DC)
- All Plastic Molded Lens, Provides an Excellent ON-OFF Contrast Ratio.
- Fast Response Time, Capable of Pulse Operation.
- High Power Luminous Intensity
- Without Stand-offs
- APPLICATIONS: Suitable for Outdoor Message Signboard, Safety equipment, automotive use.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Forward Current (DC)	${ m I_F}$	50	mA
Reverse Voltage	$ m v_R$	4	V
Power Dissipation	$P_{\mathbf{D}}$	125	mW
Operating Temperature Range	${ m T_{opr}}$	-30~85	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-40~120	°C

Unit in mm



Weight: 0.31 g

ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta = 25°C)

CHAR	ACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Forward Vo	ltage	$ m V_{f F}$	$ m I_F=20~mA$	_	1.9	2.5	V
Reverse Cu	rrent	${ m I}_{ m R}$	$V_R = 4 V$	_	_	50	μ A
Luminous	TLRH157P	IV	I _F = 20 mA (Note)	476	1700	_	mcd
Intensity	TLRH157P (ST)			850	_	4140	
Peak Emiss	ion Wavelength	$\lambda_{\mathbf{p}}$	$ m I_F=20~mA$	_	644	_	nm
Spectral Lir	ne Half Width	Δλ	$I_{ m F}=20~{ m mA}$	_	18	_	nm
Dominant V	Vavelength	$^{\lambda}{ m d}$	$I_{ m F}=20{ m mA}$	_	630	_	nm

(Note): Lamps are classified into the following ranks according to their luminous intensity. Measurement tolerance for each limit is $\pm 15\%$.

 $R:560-1120\,mcd,\,S:1000-2000\,mcd,\,T:1800-3600\,mcd.$

961001EAC2

- TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

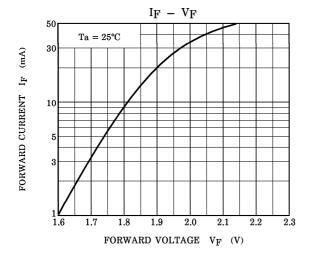
 Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.

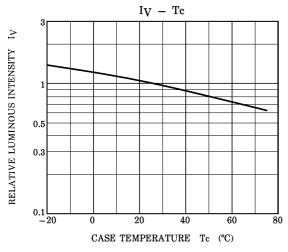
 The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication contained herein is subject to change without notice.

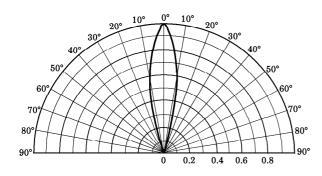
PRECAUTION

Please be careful of the followings

- Soldering temperature: 260°C max Soldering time: 3 s max (Soldering portion of lead: up to 2 mm from the body of the device)
- If the lead is formed, the lead should be formed up to 5 mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.
- This visible LED lamp also emits some IR light. If a photodetector is located near the LED lamp, please ensure that it will not be affected by this IR light.







RADIATION PATTERN

 $Ta = 25^{\circ}C$

